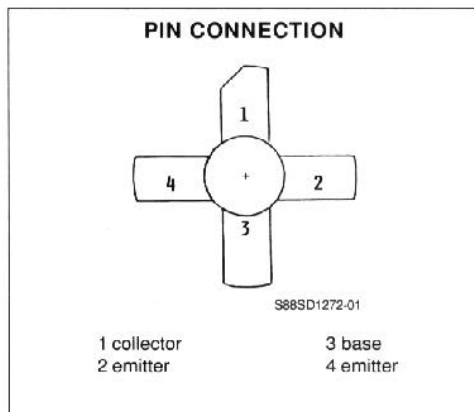
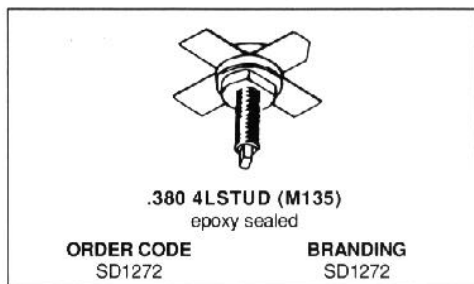


RF & MICROWAVE TRANSISTORS
130... 230MHz FM MOBILE APPLICATIONS

- FM CLASS C TRANSISTOR
- FREQUENCY 175MHz
- VOLTAGE 12.5V
- POWER OUT 25W
- POWER GAIN 9.2dB
- COMMON EMITTER


DESCRIPTION

The SD1272 is a 12.5V epitaxial silicon NPN planar transistor designed primarily for VHF communications. This device utilizes a nichrome aluminum metallization system to withstand infinite VSWR under severe operating conditions.

ABSOLUTE MAXIMUM RATINGS ($T_{case} = 25^{\circ}C$)

Symbol	Parameter	Value	Unit
V_{CBO}	Collector - Base Voltage	36.0	V
V_{CEO}	Collector - Emitter Voltage	18.0	V
V_{EB0}	Emitter - Base Voltage	4.0	V
I_C	Collector Current	4.0	A
P_{tot}	Total Power Dissipation	65.0	W
T_{stg}	Storage Temperature	- 65 to + 150	$^{\circ}C$
T_j	Junction Temperature	+ 200	$^{\circ}C$

THERMAL DATA

$R_{th(j-c)}$	Junction-case Thermal Resistance	3.5	$^{\circ}C/W$
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ELECTRICAL CHARACTERISTICS ($T_{\text{case}} = 25^{\circ}\text{C}$)

STATIC

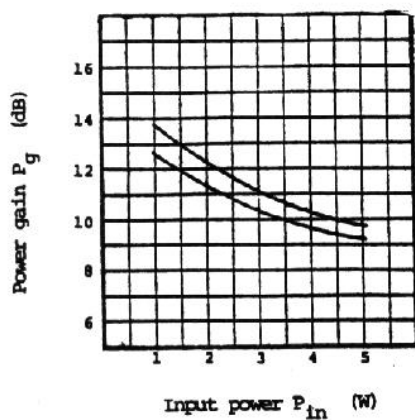
Symbol	Test Conditions		Value			Unit
			Min.	Typ.	Max.	
BV_{CBO}	$I_{\text{C}} = 20\text{mA}$	$I_{\text{E}} = 0$	36.0			V
BV_{CEO}	$I_{\text{C}} = 50\text{mA}$	$I_{\text{B}} = 0$	18.0			V
BV_{EBO}	$I_{\text{E}} = 5\text{mA}$	$I_{\text{C}} = 0$	4.0			V
I_{CBO}	$V_{\text{CB}} = 15.0\text{V}$	$I_{\text{F}} = 0$			5.0	mA
h_{FE}	$V_{\text{CE}} = 5.0\text{V}$	$I_{\text{C}} = 250\text{mA}$	5.0			

DYNAMIC

Symbol	Test Conditions			Value			Unit
				Min.	Typ.	Max.	
P_{O}	$f = 175\text{MHz}$	$V_{\text{CE}} = 12.5\text{V}$				25.0	W
G_{P}	$f = 175\text{MHz}$	$V_{\text{CE}} = 12.5\text{V}$				9.2	dB
C_{OB}	$f = 1\text{MHz}$	$V_{\text{CB}} = 15.0\text{V}$	$I_{\text{E}} = 0$			130.0	pF

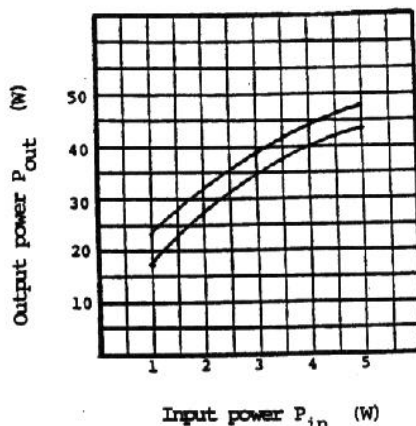
APPLICATION INFORMATION (typical curves)

POWER GAIN VS INPUT POWER



S88SD1272-02

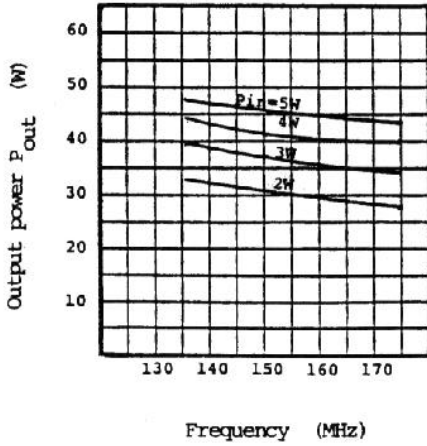
OUTPUT POWER VS INPUT POWER



S88SD1272-03

APPLICATION INFORMATION (typical curves)

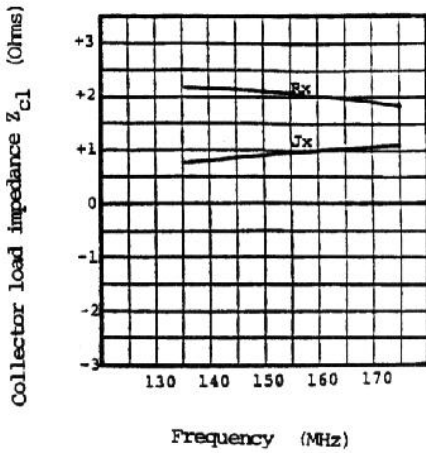
OUTPUT POWER VS FREQUENCY



S88SD1272-05

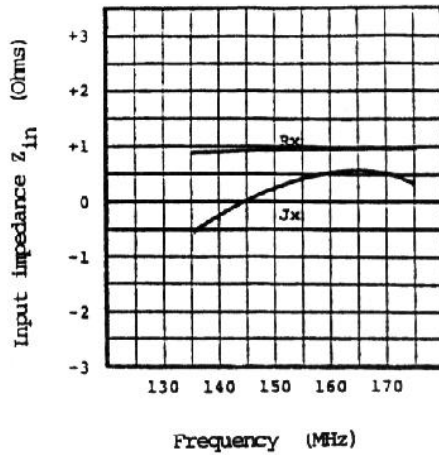
IMPEDANCE DATA (typical)

COLLECTOR LOAD IMPEDANCE VS FREQUENCY



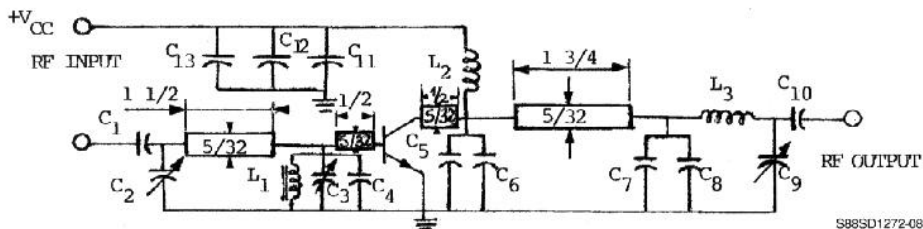
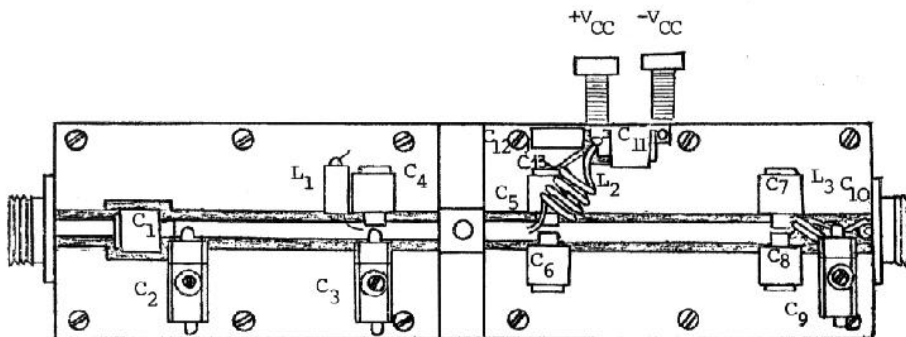
S88SD1272-07

INPUT IMPEDANCE VS FREQUENCY



S88SD1272-08

TEST CIRCUIT



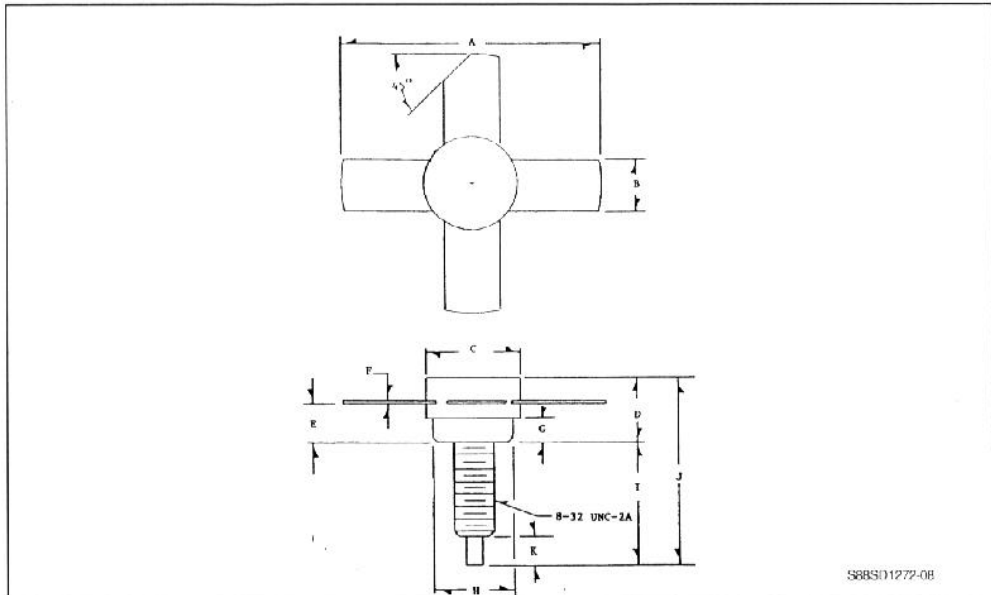
S88SD1272-08

C₁, C₁₁ : 1000pf, UNELCO
 C₂, C₃ : 24-200pf, ARCO
 C₄ : 56pf, UNELCO
 C₅, C₆ : 150pf, UNELCO
 C₇, C₈ : 51pf, UNELCO
 C₉ : 7-100pf, ARCO
 C₁₀ : 0.01μF, ERIE RED CAP

C₁₂ : 10μF, ELECTROLYTIC, 35 VDC
 C₁₃ : 0.10μF ERIE RED CAP
 L₁ : RFC, 2½ turns on VK 211/07-3B Ferrocube
 L₂ : 4 turns, # 18AWG, enameled, 3/8" I.D.
 L₃ : 2½ turns, # 18 AWG, enameled, 1/4" I.D.
 Material board double sided copper, 1/16" THK.
 3M-K-6098, mounted on 3/8 brass plates.

PACKAGE MECHANICAL DATA

.380 4LSTUD



	Minimum Inches	Maximum Inches
A	.980	
B	.220	.230
C	.370	.385
D		.275
E	.155	.175
F	.004	.007

	Minimum Inches	Maximum Inches
G	.090	.100
H	.320	.330
I	.450	.490
J		.750
K	.100	.130